

**On-water surface synthesis of electronically coupled 2D polyimide-MoS₂ van der Waals
heterostructure**

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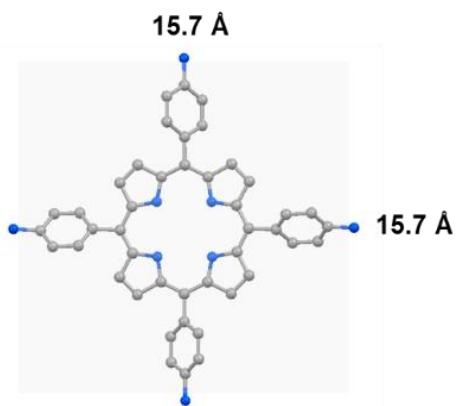
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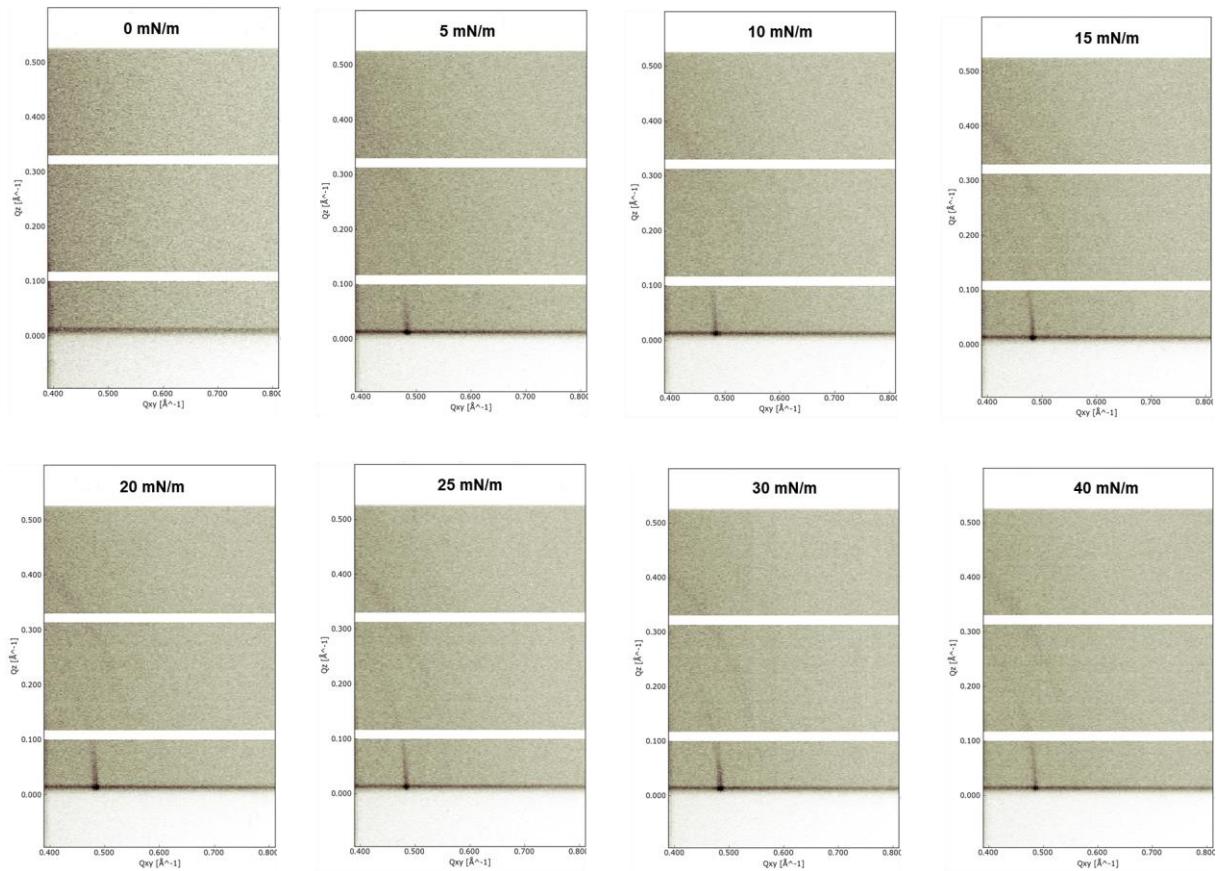
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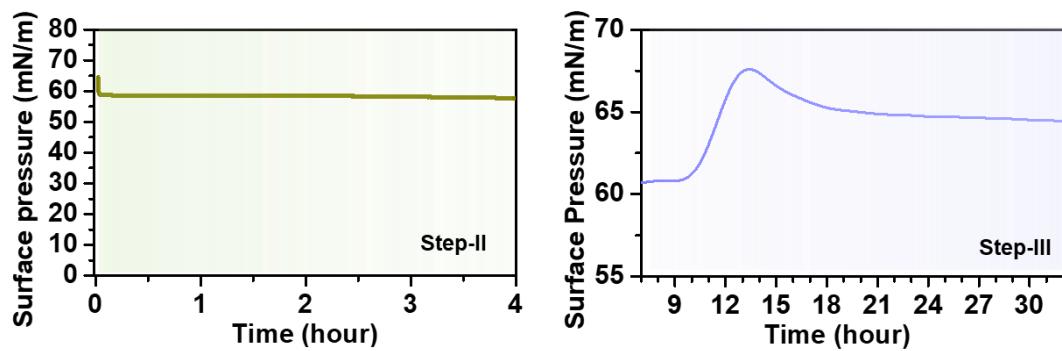
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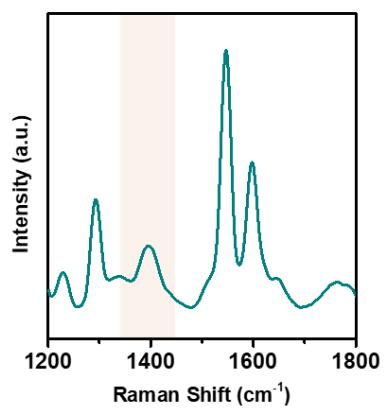
Supplementary Figure 1. The pre-organized M1 structure on the water surface exhibits the lattice parameters $a = b = 13 \text{ \AA}$ and $\gamma = 90^\circ$, which are significantly smaller than the size of an individual M1 molecule, $a = b = 15.7 \text{ \AA}$.



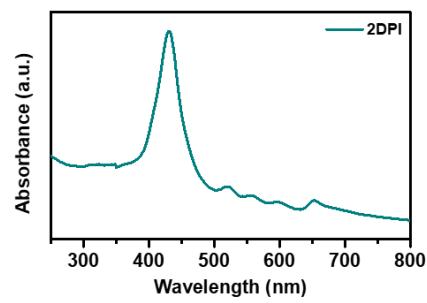
Supplementary Figure 2. *In-situ* surface-pressure dependent GIXD measurements of M1 on the water surface.



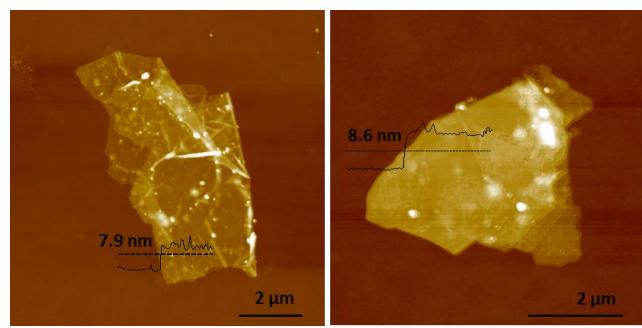
Supplementary Figure 3. The evolution of the chemical reaction involving M1 and M2 was monitored using surface pressure measurements versus time over the entire duration of the reaction, i.e., from Step-II to Step-III.



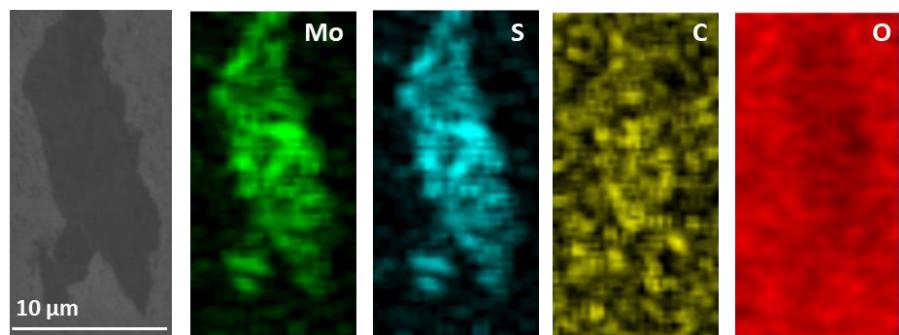
Supplementary Figure 4. The Raman spectra of 2DPI show a peak at $\sim 1403 \text{ cm}^{-1}$, indicating the formation of an imide C-N bond.



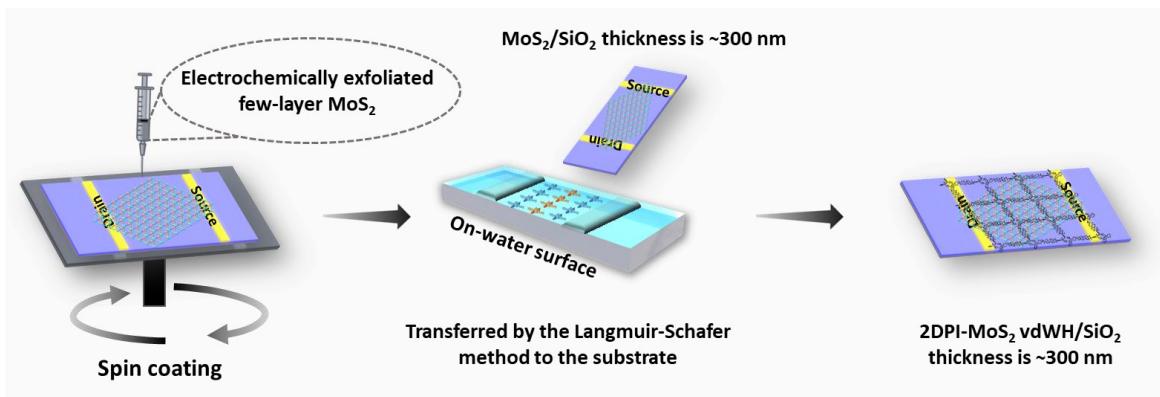
Supplementary Figure 5. Solid-state UV-Vis spectra of the as-synthesized 2DPI monolayer.



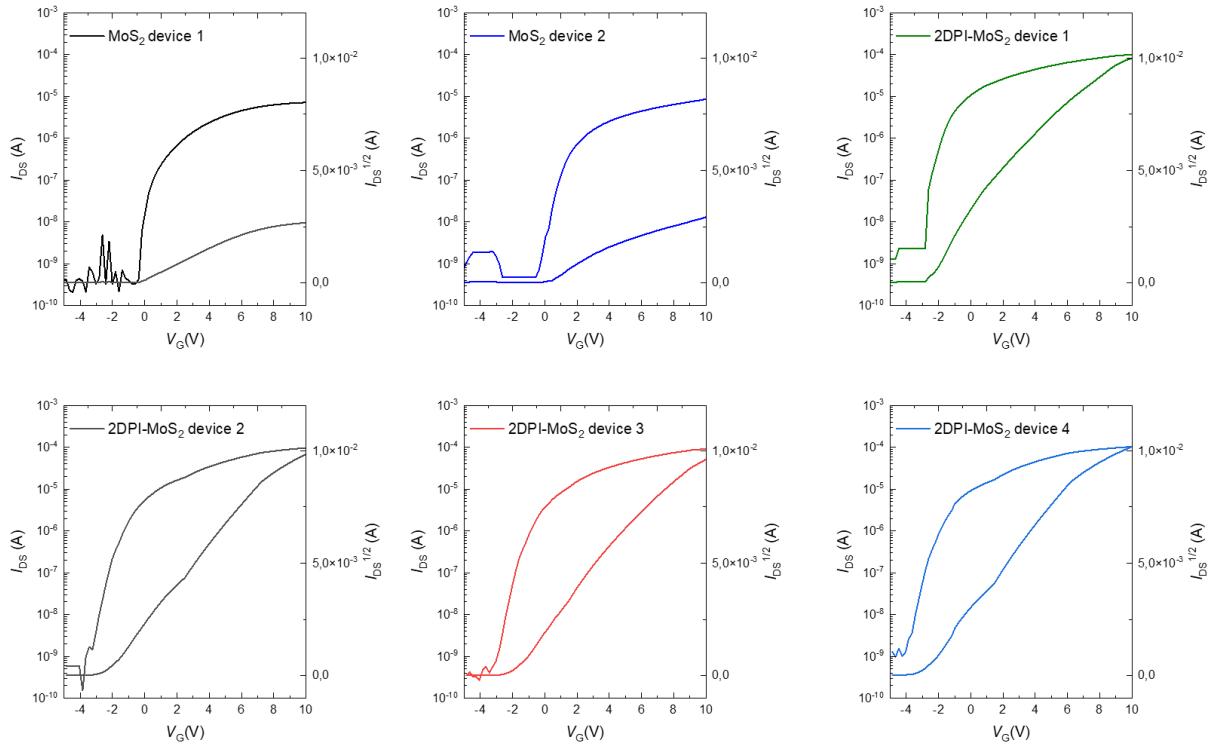
Supplementary Figure 6. AFM images of electrochemically exfoliated few-layer MoS₂.



Supplementary Figure 7. Elemental mapping of Mo, S, C, and O was performed on the 2DPI-MoS₂ vdWH film.



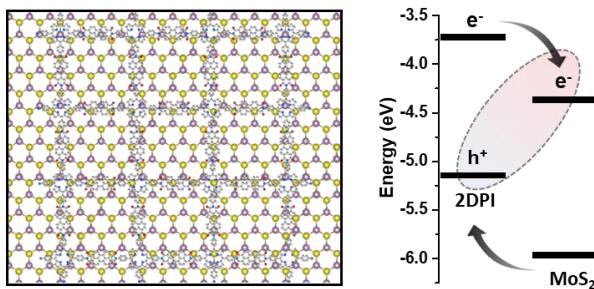
Supplementary Figure 8. Schematic of the preparation of 2DPI-MoS₂ vdWH by a wet transfer technique and the device configuration has a ¼ channel length/width ratio, and the SiO₂ thickness is approximately 300 nm.



Supplementary Figure 9. FET transfer curve of pristine MoS_2 and 2DPI- MoS_2 vdWH devices.

	Mobility		V _{th}	
	MoS_2	2DPI- MoS_2	MoS_2	2DPI- MoS_2
#1	5.4	50.0	0.0	-2.6
#2	8.0	34.4	0.5	-2.5
#3		39.6		-1.9
#4		42.3		-3.0
Average	6.72	41.59	0.23	-2.50

Supplementary Table T1. Table of statistical results for FET performance.



Supplementary Figure 10. Band alignment of 2DPI-MoS₂ vdWH^{1,2}.

The interactions between 2DPI and MoS₂

The high crystallinity of the monolayer 2DPI film offers a uniform periodic doping effect on MoS₂ in the 2DPI-MoS₂ vdWH. The Raman spectra of pristine MoS₂ displayed two distinct modes: the E_{2g} mode at 385.5 cm⁻¹, associated with in-plane vibrations of Mo and S atoms, and the A_{1g} mode at 405.07 cm⁻¹, related to the out-of-plane vibrations of S atoms. For the 2DPI-MoS₂ vdWH, a red shift of 1.22 cm⁻¹ was observed in the A_{1g} mode of MoS₂, while the E_{2g} mode remained unaltered (Figure 4g). This red shift is attributed to the stronger coupling of the A_{1g} mode with electrons in the out-of-plane direction compared to the E_{2g} mode. The enhanced FET mobility of the 2DPI-MoS₂ vdWH can be attributed to the synergistic effect of the efficient interfacial electron transfer process and the pronounced suppression of the MoS₂ lattice vibration³.

References

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